# NSN 5962-01-339-5648

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| Overall Length:  |     |
|--|-----|
| 0.840 inches   |     |
| Overall Height:  |     |
| 0.400 inches   |     |
| Body Length:   |     |
| 0.840 inches   |     |
| Body Width:  |     |
| Between 0.220 inches and 0.310 inches  |     |
| Body Height:   |     |
| Between 0.140 inches and 0.185 inches  |     |
| Maximum Power Dissipation Rating:  |     |
| 739.0 milliwatts   |     |
| Operating Tempurature Range:   |     |
| -55.0/+125.0 degrees celsius   |     |
| Storage Tempurature Range:   |     |
| -65.0/+150.0 degrees celsius   |     |
| End Application:   |     |
| Radar set an/sps-40d   |     |
| Features Provided:   |     |
| Hermetically sealed and burn in and monolithic and bipolar and programmed  |     |
| Inclosure Material:  |     |
| Ceramic  |     |
| Inclosure Configuration:   |     |
| Dual-in-line   |     |
| Output Logic Form:   |     |
| Transistor-transistor logic  |     |
| Input Circuit Pattern:   |     |
| 6 input  |     |
| Case Outline Source And Designator:  |     |
| D-2 mil-m-38510  |     |
| Current Rating Per Characteristic:   |     |
| 130.00 milliamperes supply   |     |
| Terminal Surface Treatment:  |     |
| Solder   |     |
| Voltage Rating And Type Per Characteristic:  |     |
| 7.0 volts power source   |     |
| Time Rating Per Chacteristic:  |     |
| 80.00 nanoseconds propagation delay time, high to low level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay | vel |
| output   |     |
| Memory Device Type:  |     |
| Prom   |     |
| Memory Capacity:   |     |
|  |     |

Unknown

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### Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

#### Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

# Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

Fiig:

A458a0